



EV3437-RP-00A

High Efficiency, Fully-Integrated Synchronous Boost Converter EV Board

DESCRIPTION

EV3437-RP-00A Evaluation Board is designed to demonstrate the capability of MP3437. It is a 600kHz fixed frequency, wide input range, highly integrated boost converter. It starts from an input voltage as low as 2.7V, and supports up to 20W load power from 1-cell battery.

MP3437 adopts constant-off-time (COT) control topology providing fast transient response. QFN package has MODE pin which can support mode selection of PSM, FCCM and USM in light load condition. And the integrated low-side and high-side MOSFET simplify the design and save BOM cost.

The MP3437 supports auto-pass-through mode when V_{IN} is higher than $V_{OUT-SET}$ in PSM mode. It also features with programmable input under-voltage lockout (UVLO) and over temperature protection.

The MP3437 is available in QFN-10 (2mmx2.5mm) and TSOT23-8 package. This board is available in QFN-10 package.

ELECTRICAL SPECIFICATION

Parameter	Symbol	Value	Units
Input Voltage	V_{IN}	2.7-16	V
Output Voltage	V_{OUT}	8	V
Output Current	I_{OUT}	2.5	A

FEATURES

- 2.7V-to-16V Startup Voltage⁽¹⁾
- 0.8V-to-16V Operation Voltage
- Up to 16V Output Voltage
- Support 20W Power Load from 3.3V
- 9.5A Internal Switch Current Limit
- Integrated 14mΩ & 21mΩ Power MOSFET
- >90% Efficiency for 3.3V VIN to 8V/2.5A
- Auto Pass-Through Function in PSM Mode
- 600kHz Fixed Switching Frequency
- Adaptive COT for Fast Transient Response
- Internal Soft Start and Compensation
- Programmable UVLO and Hysteresis
- 150°C Over Temperature Protection
- Over Voltage Protection
- QFN-10 Package on This Board

APPLICATIONS

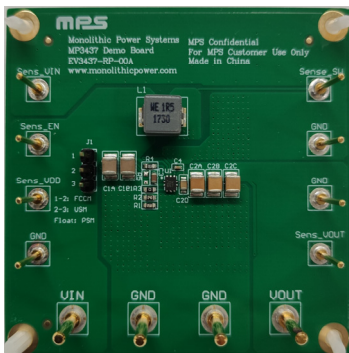
- Notebook
- AI Speaker
- Bluetooth Speaker
- Portable POS System

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Note:

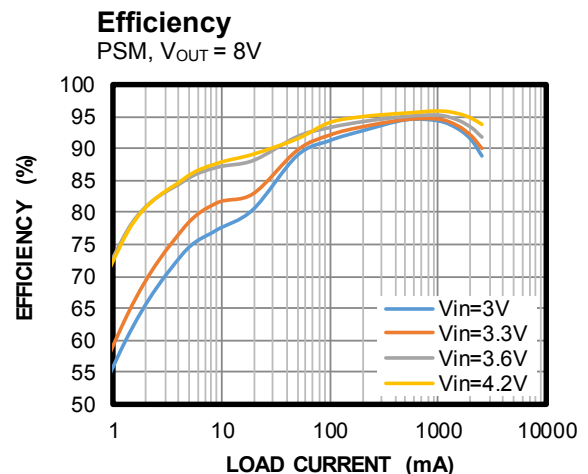
(1) During input power on, the inrush current through high-side MOSFET body diode should be limited less than 30A. And the continuous current should be avoided to flow through high-side MOSFET body diode. Refer to "Input Power-up Inrush Current Control" section in MP3437 datasheet for detail.

EV3437-RP-00A EVALUATION BOARD

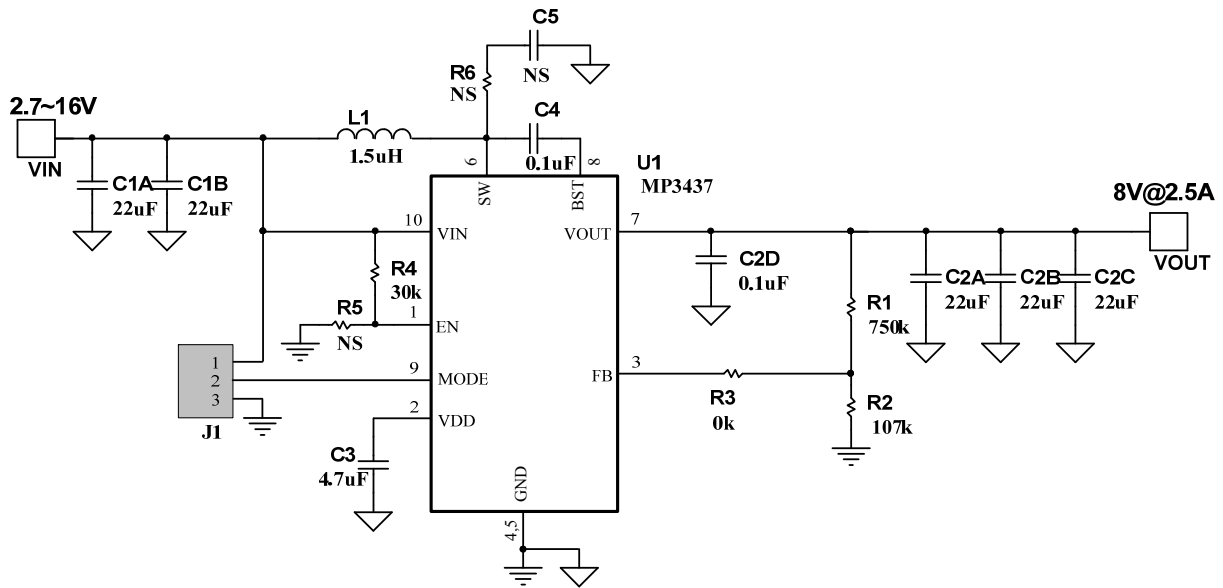


(L x W x H) 6.4cm x 6.4cm x 0.6cm

Board Number	MPS IC Number
EV3437-RP-00A	MP3437GRP



EVALUATION BOARD SCHEMATIC

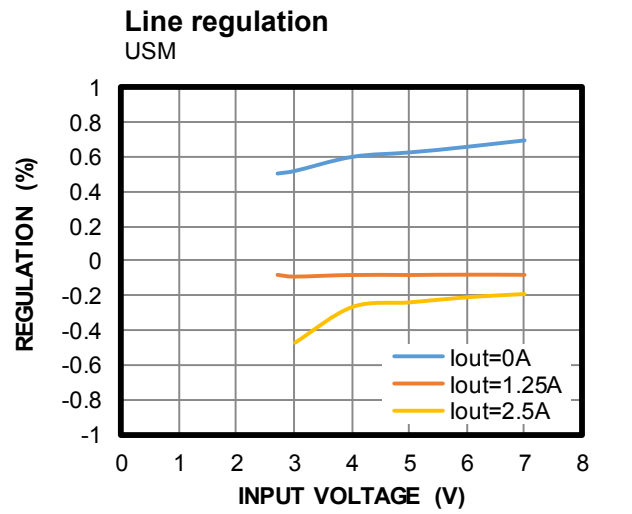
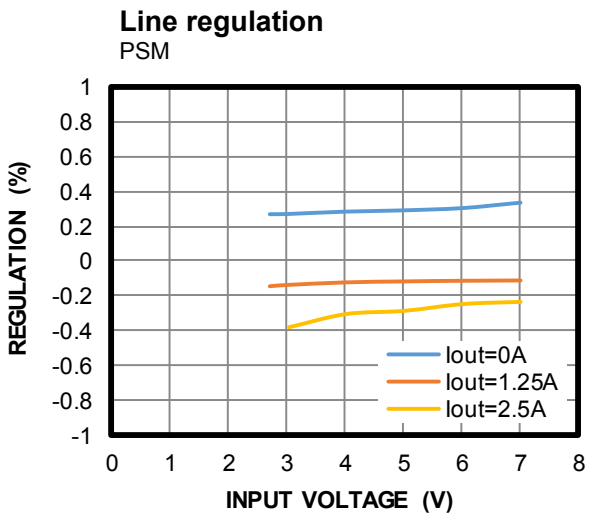
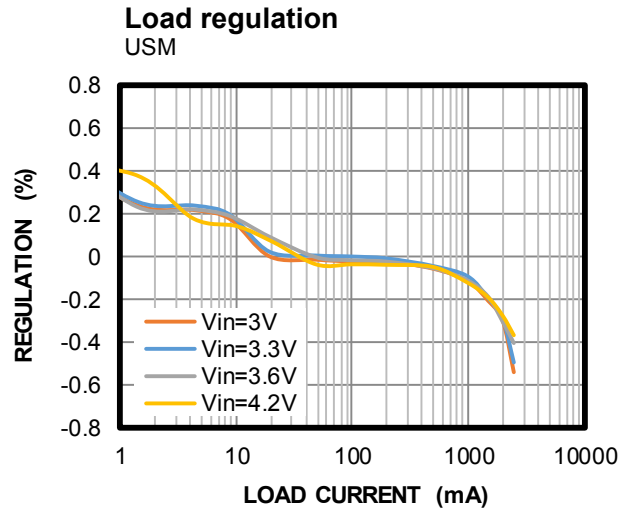
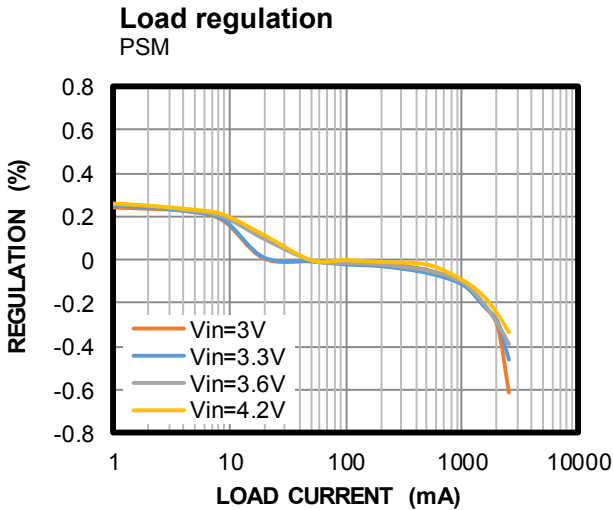
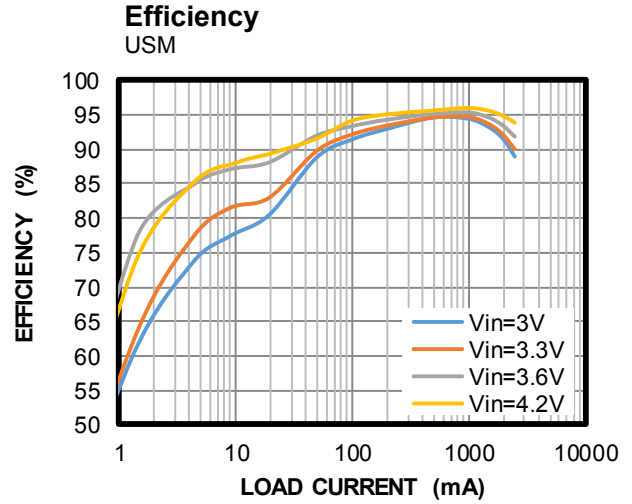
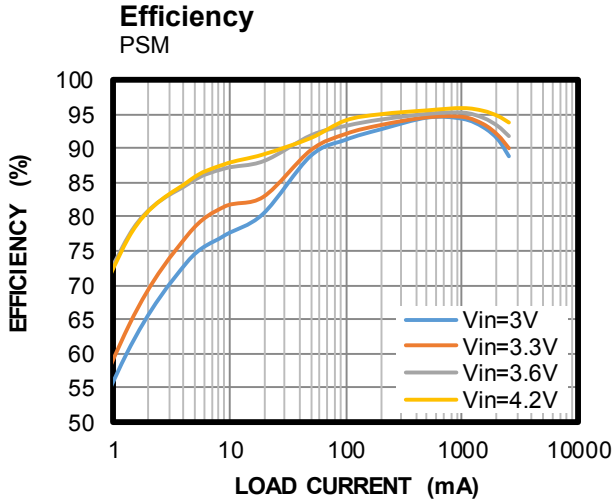


EV3437-RP-00A BILL OF MATERIALS

Qty	Ref	Value	Description	Package	Manufacturer	Manufacturer P/N
5	C1A,C1B C2A,C2B, C2C	22 μ F	Ceramic Cap.,25V,X7R	1210	Murata	GRM32ER71E226KE 20L
1	C2D	100nF	Ceramic Cap.,25V,X7R	0805	Murata	GRM21BR71E104KA 01L
1	C3	4.7 μ F	Ceramic Cap.,16V,X7R	0603	Murata	GRM188Z71C475KE 21D
1	C4	100nF	Ceramic Cap.,25V,X7R	0402	Murata	GRM155R71E104KA 88D
1	R1	750K	Film Res,1%	0603	YAGEO	RC0603FR-07750KL
1	R2	107K	Film Res,1%	0603	YAGEO	RC0603FR-07107KL
1	R3	0R	Film Res,1%	0603	YAGEO	RC0603FR-070RL
1	R4	30K	Film Res,1%	0603	YAGEO	RC0603FR-0730KL
0	R5, R6, C5	NS				
1	L1	1.5 μ H	Inductor, RDC=8.6mOhm, Isat=14.5A	SMD	Wruth	74437349015
1	J1	JUMPER	Jumper,1*3Pins	DIP	WE	60900213421
1	U1	MP3437	16V/9.5A Boost	QFN-10	MPS	MP3437GRP

EVB TEST RESULTS

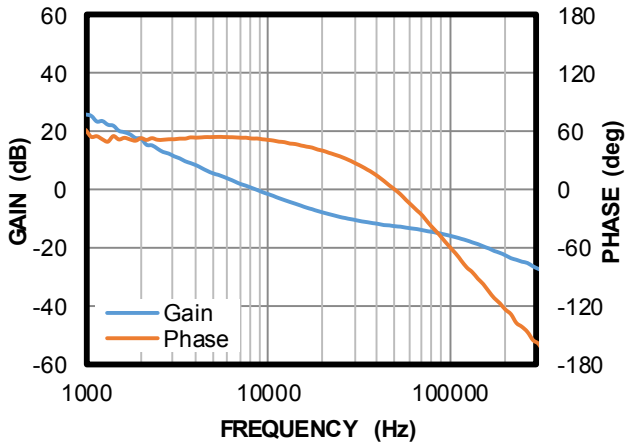
$V_{IN} = 3.3V$, $V_{OUT} = 8V$, $L = 1.5\mu H$, $I_{OUT} = 2.5A$, PSM, $T_A = 25^\circ C$, unless otherwise noted.



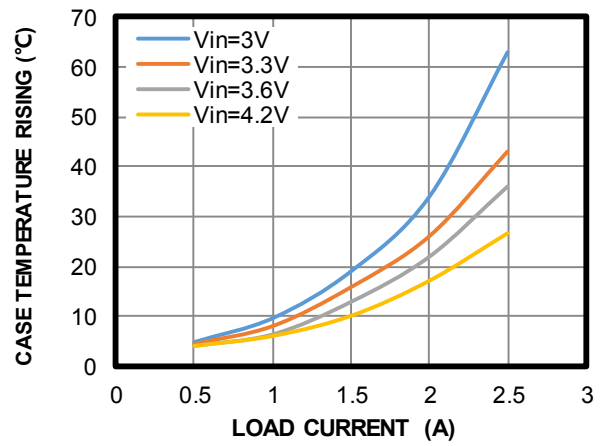
EVB TEST RESULTS (continued)

$V_{IN} = 3.3V$, $V_{OUT} = 8V$, $L = 1.5\mu H$, $I_{OUT} = 2.5A$, PSM, $T_A = 25^\circ C$, unless otherwise noted.

Bode Plot



Case Temperature Rising

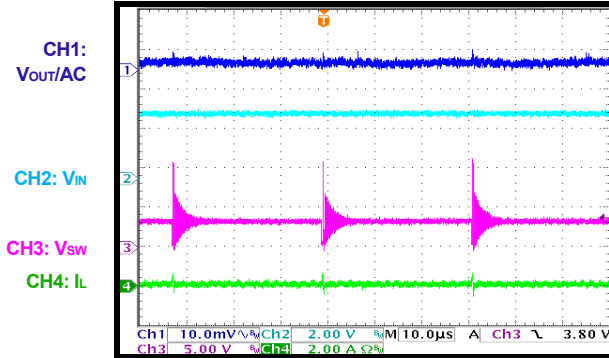


EVB TEST RESULTS (continued)

$V_{IN} = 3.3V$, $V_{OUT} = 8V$, $L = 1.5\mu H$, $I_{OUT} = 2.5A$, PSM, $T_A = 25^\circ C$, unless otherwise noted.

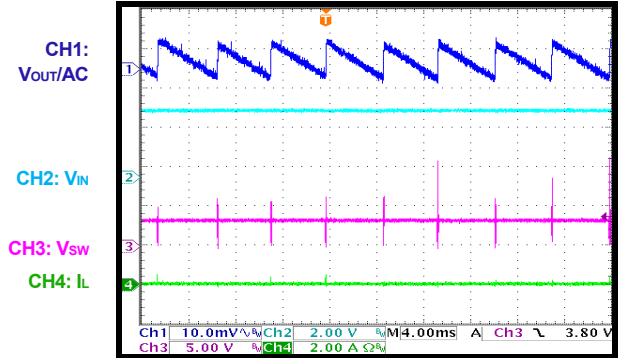
Steady State

$I_{OUT} = 0A$, USM



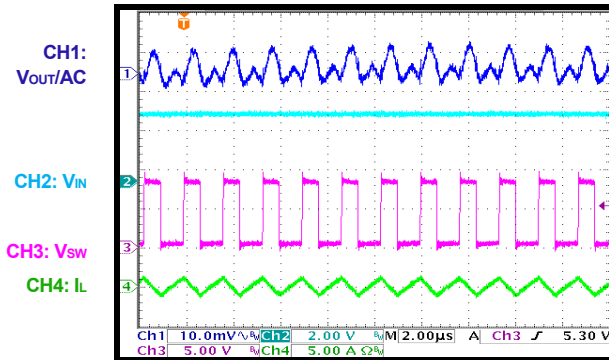
Steady State

$I_{OUT} = 0A$, PSM



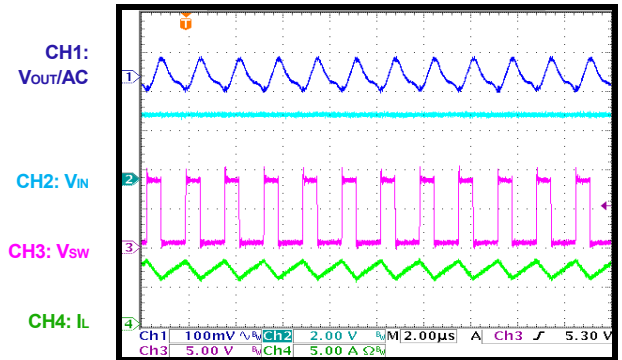
Steady State

$I_{OUT} = 0A$, FCCM



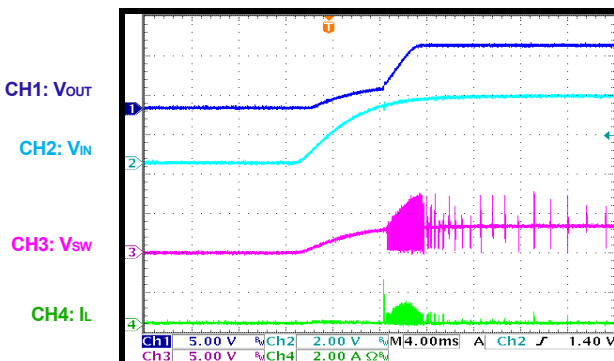
Steady State

$I_{OUT} = 2.5A$



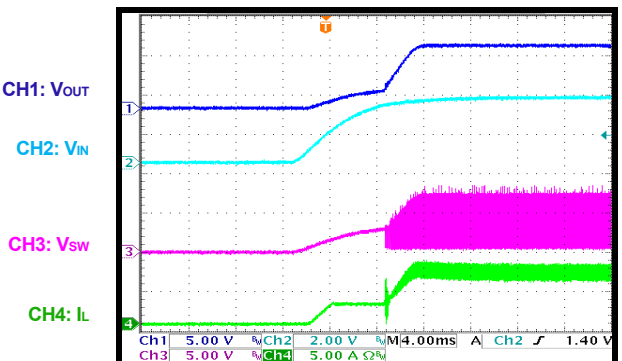
VIN Start-Up

$I_{OUT} = 0A$



VIN Start-Up

$I_{OUT} = 2.5A$

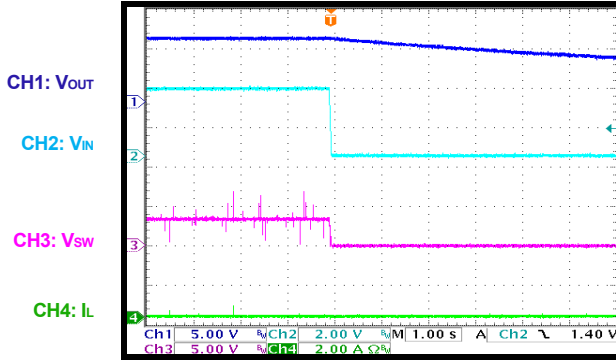


EVB TEST RESULTS *(continued)*

$V_{IN} = 3.3V$, $V_{OUT} = 8V$, $L = 1.5\mu H$, $I_{OUT} = 2.5A$, PSM, $T_A = 25^\circ C$, unless otherwise noted.

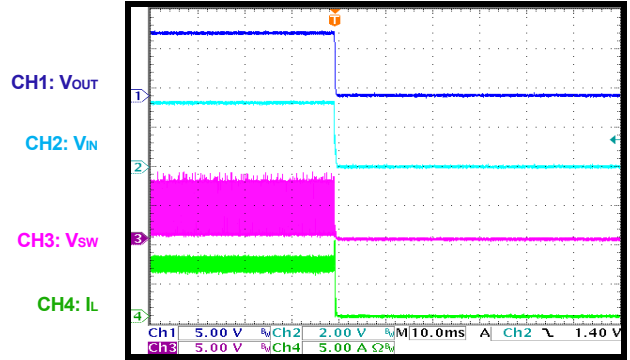
VIN Shutdown

$I_{OUT} = 0A$



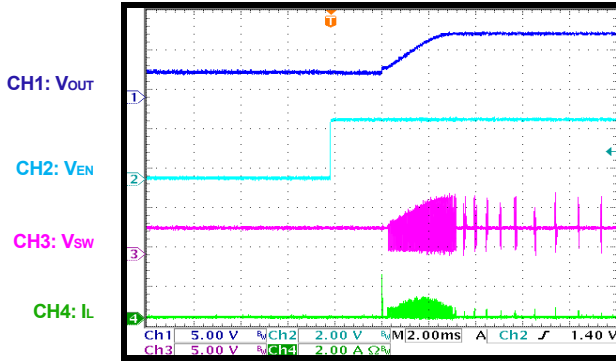
VIN Shutdown

$I_{OUT} = 2.5A$



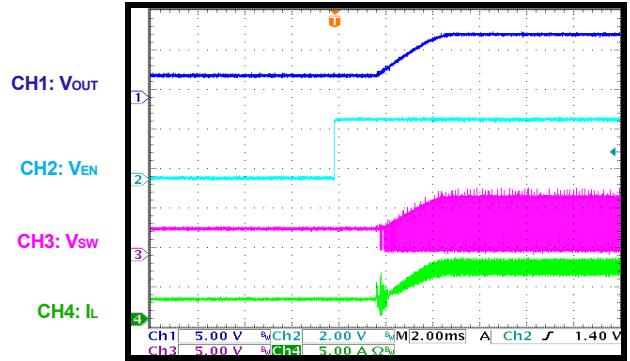
EN Start-Up

$I_{OUT} = 0A$



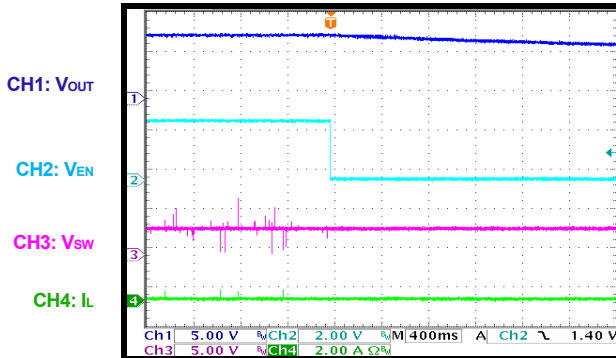
EN Start-Up

$I_{OUT} = 2.5A$



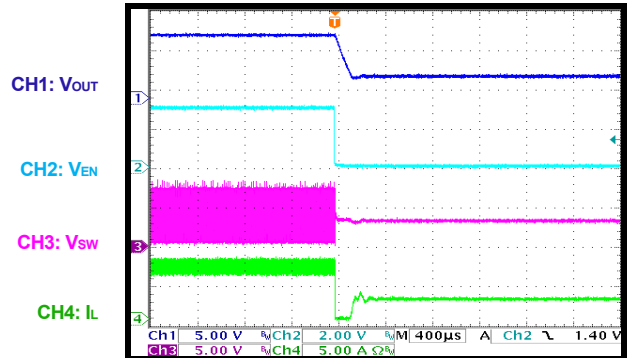
EN Shutdown

$I_{OUT} = 0A$



EN Shutdown

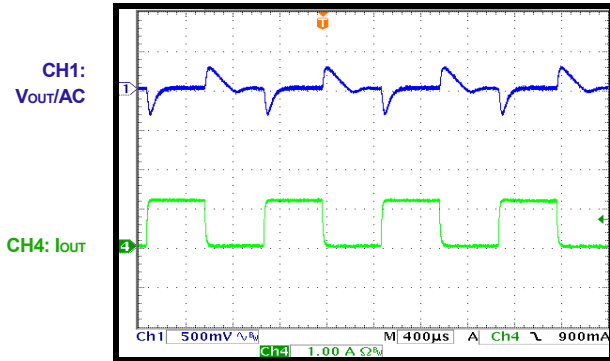
$I_{OUT} = 2.5A$



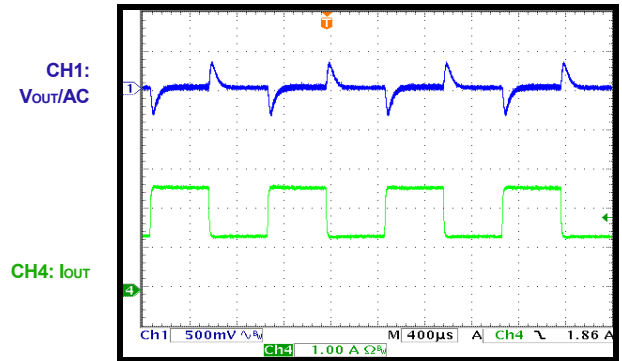
EVB TEST RESULTS (continued)

$V_{IN} = 3.3V$, $V_{OUT} = 8V$, $L = 1.5\mu H$, $I_{OUT} = 2.5A$, PSM, $T_A = 25^\circ C$, unless otherwise noted.

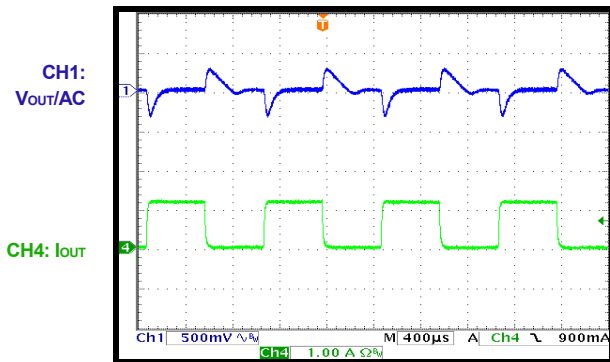
Load Transient
 $I_{OUT} = 0 - 1.25A$, USM



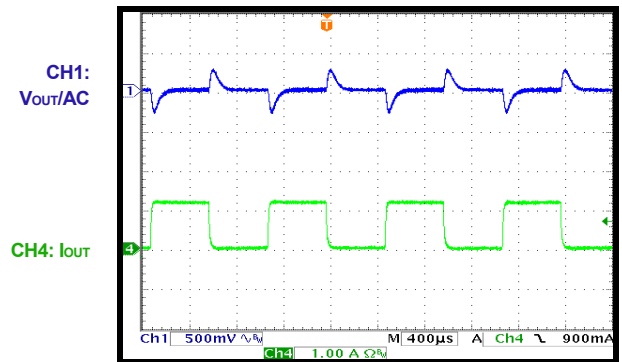
Load Transient
 $I_{OUT} = 1.25 - 2.5A$



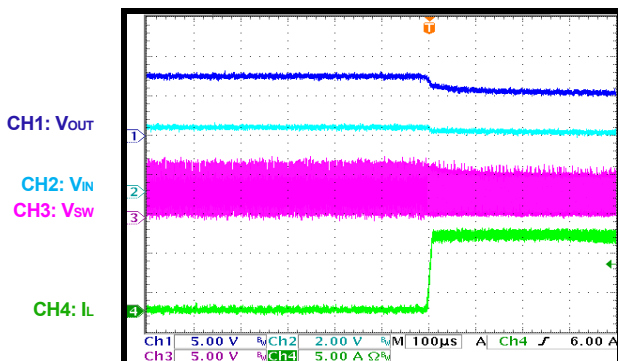
Load Transient
 $I_{OUT} = 0 - 1.25A$, PSM



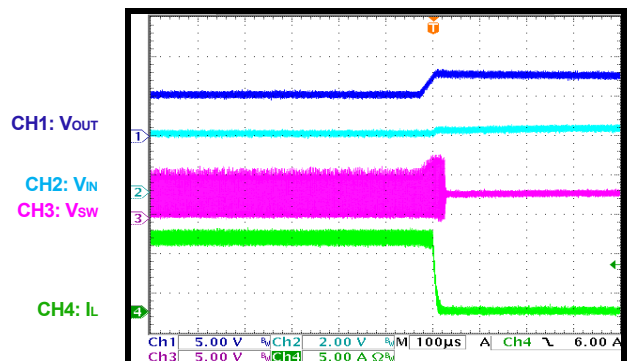
Load Transient
 $I_{OUT} = 0 - 1.25A$, FCCM



Over-Current Entry
Increase output current slowly, 0A->4.5A



Over-Current Recovery
Decrease output current slowly, 4.5A->0A



PRINTED CIRCUIT BOARD LAYOUT

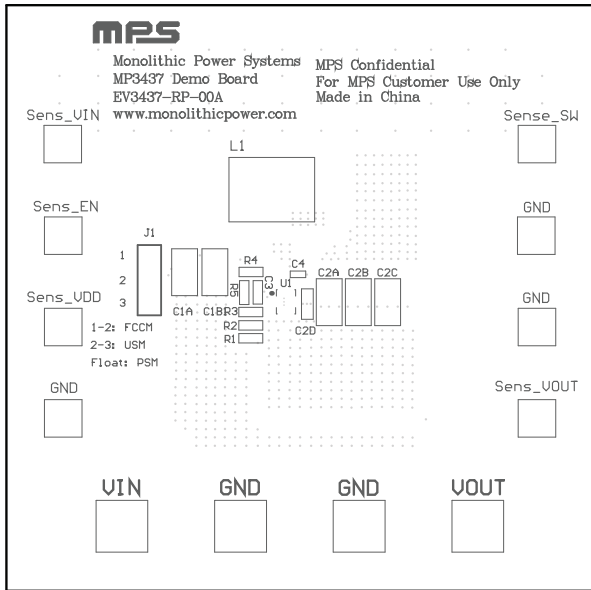


Figure 1: Top Silk

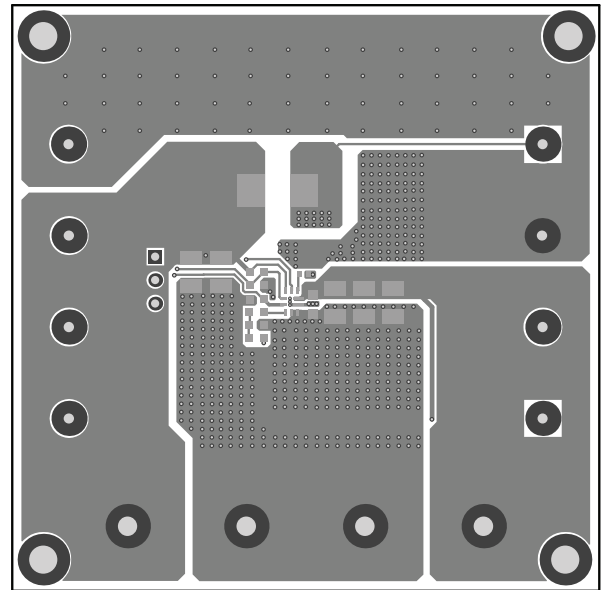


Figure 2: Top Layer

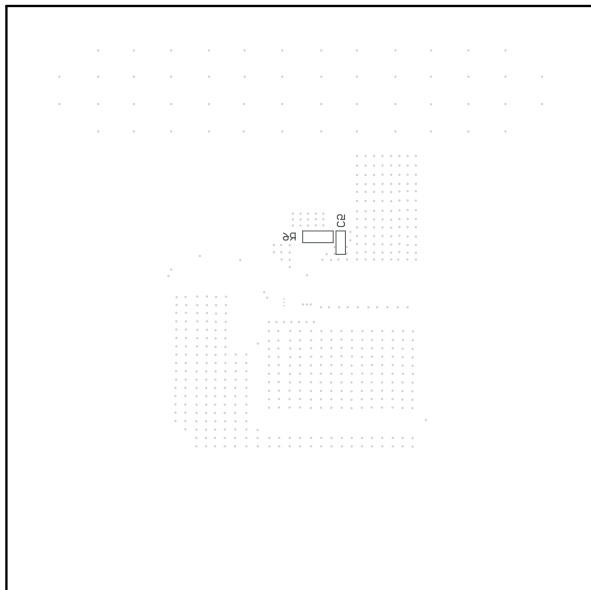


Figure 3: Bottom Silk

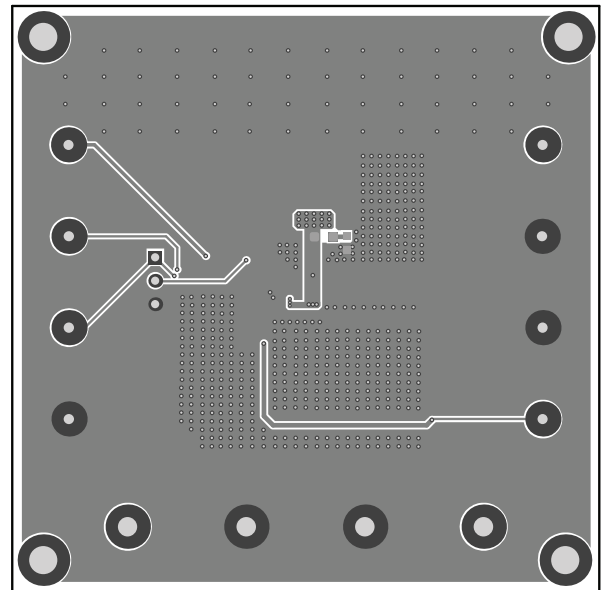


Figure 4: Bottom Layer